onsemi

Silicon Carbide (SiC) Diode – EliteSiC, TO247-3, 20 A, 650 V SiC Merged PiN-Schottky (MPS) Diode

UJ3D06520KSD

Description

onsemi offers the 3rd generation of high performance SiC Merged-PiN-Schottky (MPS) diodes. With zero reverse recovery charge and 175 °C maximum junction temperature, these diodes are ideally suited for high frequency and high efficiency power systems with minimum cooling requirements.

Features

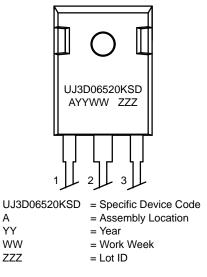
- 175 °C Maximum Operating Junction Temperature
- Easy Paralleling
- Extremely Fast Switching not Dependent on Temperature
- No Reverse or Forward Recovery
- Enhanced Surge Current Capability, MPS Structure
- Excellent Thermal Performance, Ag Sintered
- 100% UIS Tested
- This Device is Pb-Free, Halogen Free and is ROHS Compliant

Typical Applications

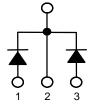
- Power Converters
- Industrial Motor Drives
- Switching-mode Power Supplies
- Power Factor Correction Modules



MARKING DIAGRAM







ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

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MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Value (Leg/Device)	Unit	
DC Blocking Voltage	V _R		650	V	
Repetitive Peak Reverse Voltage, $T_J = 25 \ ^{\circ}C$	V _{RRM}		650	V	
Surge Peak Reverse Voltage	V _{RSM}		650	V	
Maximum DC Forward Current	١ _F	T _C = 152 °C	10/20	А	
Non-repetitive Forward Surge Current Sine	I _{FSM}	$T_{C} = 25 \ ^{\circ}C, t_{p} = 10 \ \text{ms}$	70/140	A	
Halfwave		$T_{C} = 110 \ ^{\circ}C, t_{p} = 10 \ \text{ms}$	60/120		
Repetitive Forward Surge Current Sine	I _{FRM}	$T_{C} = 25 \ ^{\circ}C, t_{p} = 10 \ \text{ms}$	45.9/91.8	А	
Halfwave, D = 0.1		$T_{C} = 110 \ ^{\circ}C, t_{p} = 10 \ \text{ms}$	28.7/57.4	1	
Non-repetitive Peak Forward Current	I _{F, max}	T _C = 25 °C, t _p = 10 μs	455/910	А	
		$T_{C} = 110 \ ^{\circ}C, t_{p} = 10 \ \mu s$	455/910		
i ² t Value	∫i ² dt	$T_{C} = 25 \ ^{\circ}C, t_{p} = 10 \ \text{ms}$	24.5/98	A ² s	
		$T_{C} = 110 \ ^{\circ}C, t_{p} = 10 \ \text{ms}$	18/72		
Power Dissipation	P _{tot}	T _C = 25 °C	136.4/272.8	W	
		T _C = 152 °C	20.9/41.8		
Maximum Junction Temperature	T _{J, max}		175	°C	
Operating and Storage Temperature	T_J, T_{STG}		-55 to 175	°C	
Soldering Temperatures, Wavesoldering only Allowed at Leads	T _{sold}	1.6 mm from case for 10 s	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS (T_J = +25 °C unless otherwise specified)

			Value (Leg/Device)			
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Forward Voltage	V _F	I_F = 10 A/20 A, T_J = 25 °C	-	1.5	1.7	V
		$I_F = 10 \text{ A}/20 \text{ A}, \text{ T}_J = 150 \ ^\circ\text{C}$	-	1.68	2	
		I_F = 10 A/20 A, T_J = 175 °C	-	1.75	2.1	
Reverse Current	I _R	V_R = 650 V, T_J = 25 °C	-	10/20	60/120	μΑ
		V_R = 650 V, T_J = 175 °C	-	150/300	-	
Total Capacitive Charge (Note 1)	Q _C	V _R = 400 V	-	23/46	-	nC
Total Capacitance	С	V _R = 1 V, f = 1 MHz	-	327/654	-	pF
		V _R = 300 V, f = 1 MHz	-	38/76	-	
		V _R = 600 V, f = 1 MHz	-	34/68	-	
Capacitance Stored Energy	E _C	V _R = 400 V	-	3.4/6.8	-	μJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Q_C is independent on T_J, di_F/dt, and I_F as shown in the application note <u>AND90316/D</u>

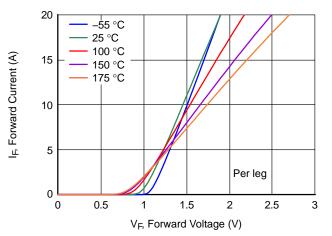
THERMAL CHARACTERISTICS

			Value (Leg/Device)		vice)	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Thermal Resistance	$R_{ ext{ heta}JC}$		-	0.82/0.41	1.1/0.55	°C/W

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TYPICAL PERFORMANCE

I_F, Forward Current (A)





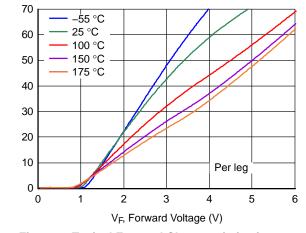


Figure 2. Typical Forward Characteristics in Surge Current per Leg

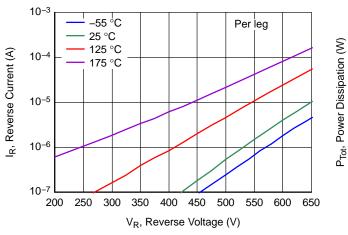


Figure 3. Typical Reverse Characteristics per Leg

I_F, Forward Current (A)

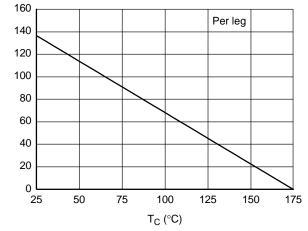
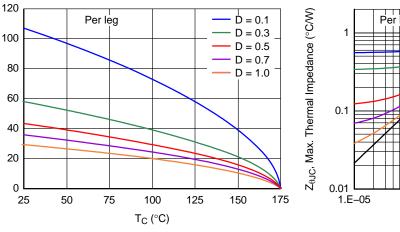
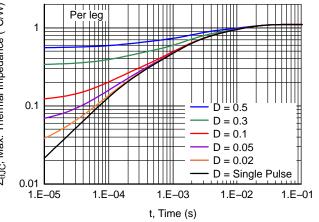
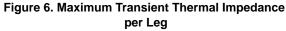


Figure 4. Power Dissipation per Leg









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TYPICAL PERFORMANCE (CONTINUED)

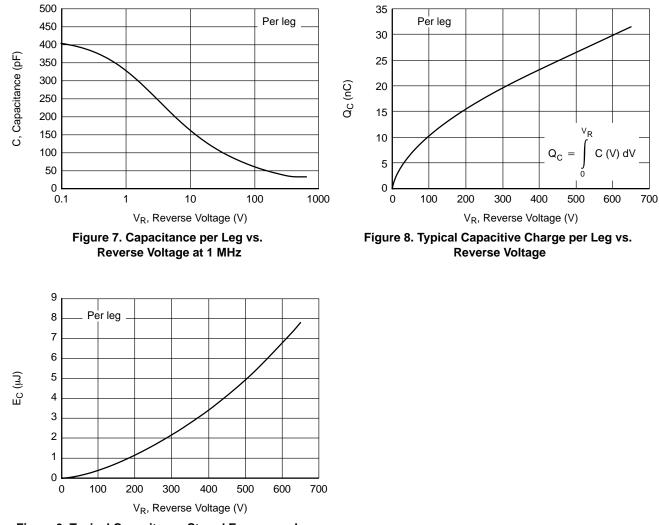


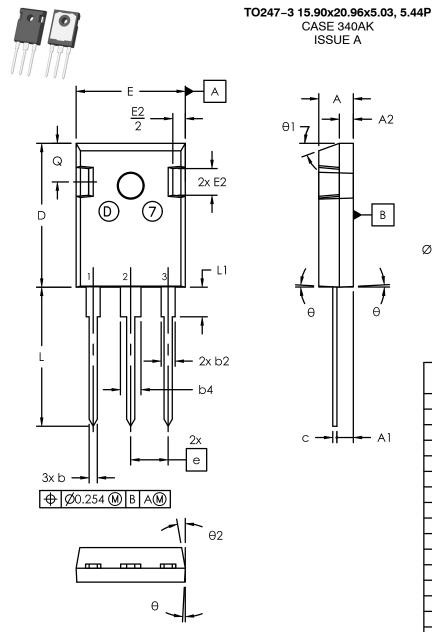
Figure 9. Typical Capacitance Stored Energy per Leg vs. Reverse Voltage

ORDERING INFORMATION

Part Number	Marking	Package	Shipping
UJ3D06520KSD	UJ3D06520KSD	TO247-3 (Pb-Free, Halogen Free)	600 / Tube

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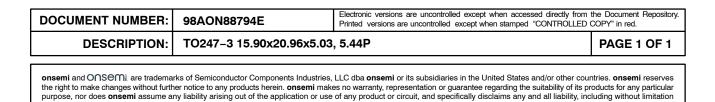
⊕ Ø0.635 M B AM



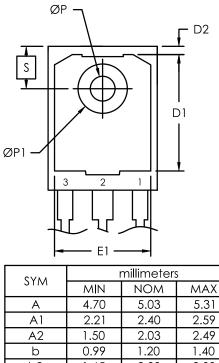
NOTE:

- 1. Dimensioning and tolerancing as per ASME Y14.5 2018
- 2. Controlling dimension : millimeters
- 3. Package Outline in compliance with JEDEC standard var. AD.
- 4. Dimensions D & E does not include mold flash.
- 5. ØP to have max draft angle of 1.7° to the top with max. hole diameter of 3.91mm.

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DATE 12 FEB 2025



А	4.70	5.03	5.31		
A1	2.21	2.40	2.59		
A2	1.50	2.03	2.49		
b	0.99	1.20	1.40		
b2	1.65	2.03	2.39		
b4	2.59	3.00	3.43		
С	0.38	0.60	0.89		
D	20.70	20.96	21.46		
D1	13.08	-	-		
D2	0.51	1.19	1.35		
E	15.49	15.90	16.26		
е	5.44 BSC				
E1	13.00	14.02	13.60		
E2	3.43	3.89	5.20		
L	19.62	20.27	20.32		
L1	1	-	4.50		
ØP	3.40	3.60	3.80		
ØP1	7.06	7.19	7.39		
Q	5.38	5.62	6.20		
S	6.15 BSC				
θ	3°				
θ1	20°				
θ2	10°				

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Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>